

Supplementary Materials: The Influence of Different Partial Pressures on the Fabrication of InGaO Ultraviolet Photodetectors

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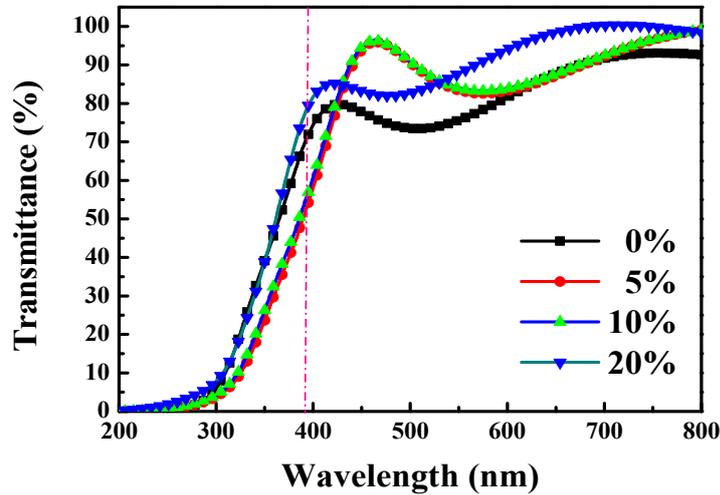


Figure S1. Transmittance spectra of different partial pressure on IGO films.

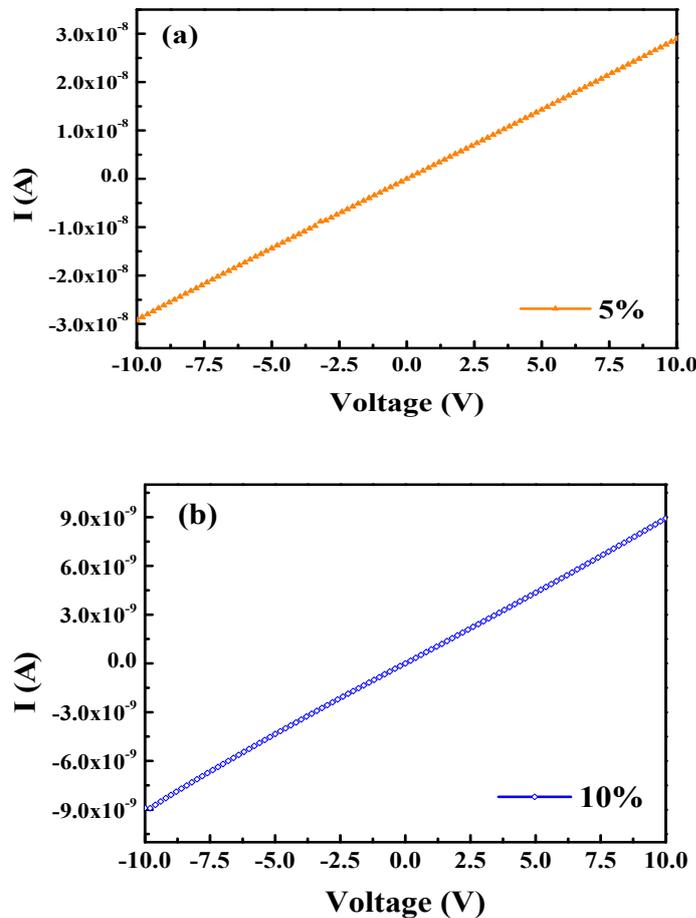


Figure S2. The linear dark I-V characteristics curve of the IGO thin films MSM photodetector fabricated under $pO_2 =$ (a) 5% (b) 10% in linear scale.

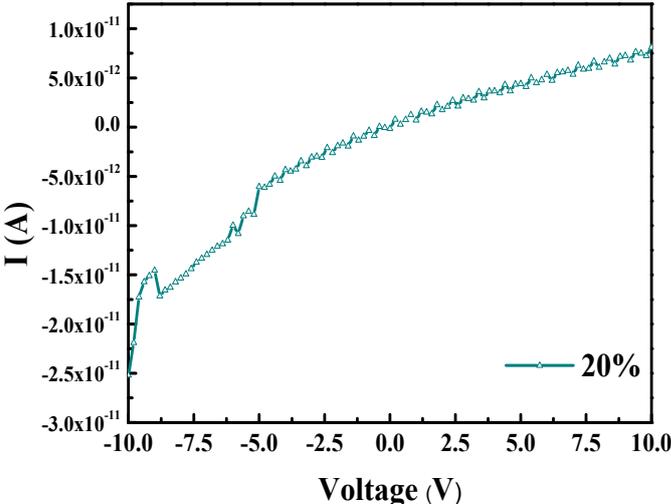


Figure S3. The Schottky dark I-V characteristics curve of the IGO thin films MSM photodetector fabricated under $pO_2 = 20\%$ in linear scale.